

MMDT3906TB6

DUAL PNP GENERAL PURPOSE SWITCHING TRANSISTOR

VOLTAGE 40 Volt **POWER** 200 mWatt

SOT-563 Unit: inch (mm)

FEATURES

- PNP epitaxial silicon, planar design
 - Collector-emitter voltage $V_{CE} = -40V$
 - Collector current $I_C = -200mA$
 - Lead free in compliance with EU RoHS 2.0
- Ç Green molding compound as per IEC 61249 standard

MECHANICAL DATA

- Case: SOT-563, Plastic
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0001 ounces, 0.0026 grams.
- Marking: TS

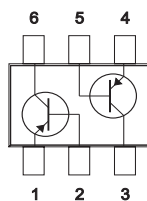
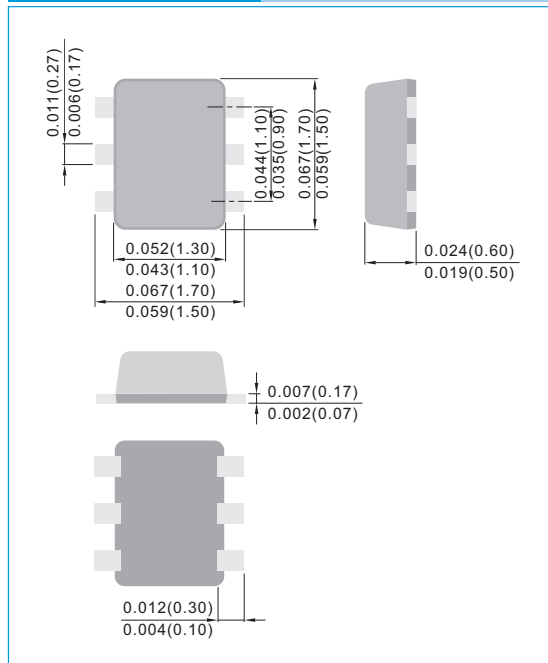


Fig.53



ABSOLUTE RATINGS

PARAMETER	Symbol	Value	Units
Collector - Emitter Voltage	V_{CEO}	-40	V
Collector - Base Voltage	V_{CBO}	-40	V
Emitter - Base Voltage	V_{EBO}	-5.0	V
Collector Current - Continuous	I_C	-200	mA

THERMAL CHARACTERISTICS

Parameter	Symbol	Value	Units
Max Power Dissipation (Note 1)	P_{TOT}	200	mW
Thermal Resistance , Junction to Ambient	$R_{\theta JA}$	625	°C/W
Junction Temperature	T_J	-55 to 150	°C
Storage Temperature	T_{STG}	-55 to 150	°C

Note 1: Transistor mounted on FR-4 board 70 x 60 x 1mm.

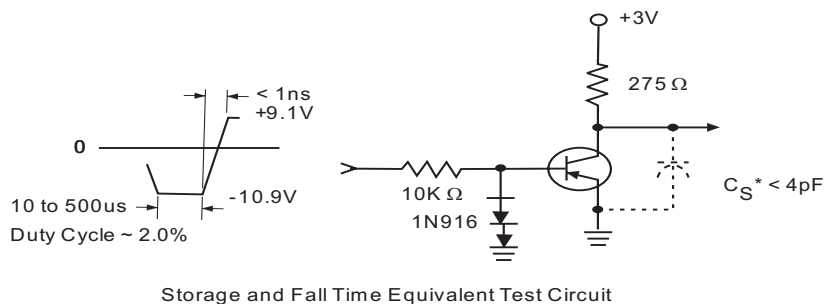
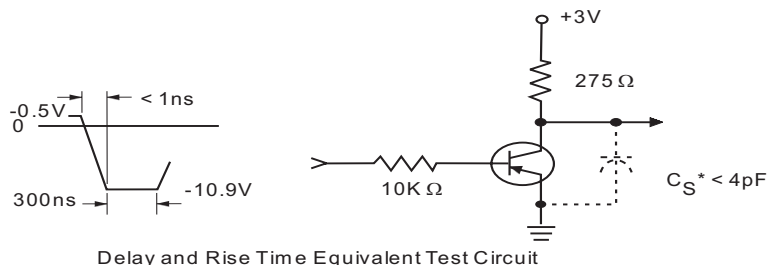
MMDT3906TB6

ELECTRICAL CHARACTERISTICS

PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1.0\text{mA}, I_B = 0$	-40	-	-	V
Collector - Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu\text{A}, I_E = 0$	-40	-	-	V
Emitter - Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu\text{A}, I_C = 0$	-5.0	-	-	V
Base Cutoff Current	I_{BI}	$V_{CE} = -30\text{V}, V_{EB} = -3.0\text{V}$	-	-	-50	nA
Collector Cutoff Current	I_{CEX}	$V_{CE} = -30\text{V}, V_{EB} = -3.0\text{V}$	-	-	-50	nA
DC Current Gain (Note 2)	h_{FE}	$I_C = -0.1\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -1.0\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -10\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -50\text{mA}, V_{CE} = -1.0\text{V}$ $I_C = -100\text{mA}, V_{CE} = -1.0\text{V}$	60 80 100 60 30	- - - - -	- - 300 - -	-
Collector - Emitter Saturation Voltage (Note 2)	$V_{CE(SAT)}$	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$	-	-	-0.25 -0.4	V
Base - Emitter Saturation Voltage (Note 2)	$V_{BE(SAT)}$	$I_C = -10\text{mA}, I_B = -1.0\text{mA}$ $I_C = -50\text{mA}, I_B = -5.0\text{mA}$	-0.65 -	- -	-0.85 -0.95	V
Collector - Base Capacitance	C_{CBO}	$V_{CB} = -5\text{V}, I_E = 0, f = 1\text{MHz}$	-	-	4.0	pF
Emitter - Base Capacitance	C_{EBO}	$V_{CB} = -0.5\text{V}, I_C = 0, f = 1\text{MHz}$	-	-	10	pF
Delay Time	t_d	$V_{CC} = -3\text{V}, V_{BE} = -0.5\text{V}, I_C = -10\text{mA}, I_B = -1.0\text{mA}$	-	-	35	ns
Rise Time	t_r	$V_{CC} = -3\text{V}, V_{BE} = -0.5\text{V}, I_C = -10\text{mA}, I_B = -1.0\text{mA}$	-	-	35	ns
Storage Time	t_s	$V_{CC} = -3\text{V}, I_C = -10\text{mA}, I_{B1} = I_{B2} = -1.0\text{mA}$	-	-	225	ns
Fall Time	t_f	$V_{CC} = -3\text{V}, I_C = -10\text{mA}, I_{B1} = I_{B2} = 1.0\text{mA}$	-	-	75	ns

Note 2: Pulse Test: Pulse Width < 300 us, Duty Cycle < 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS



MMDT3906TB6

ELECTRICAL CHARACTERISTICS CURVE

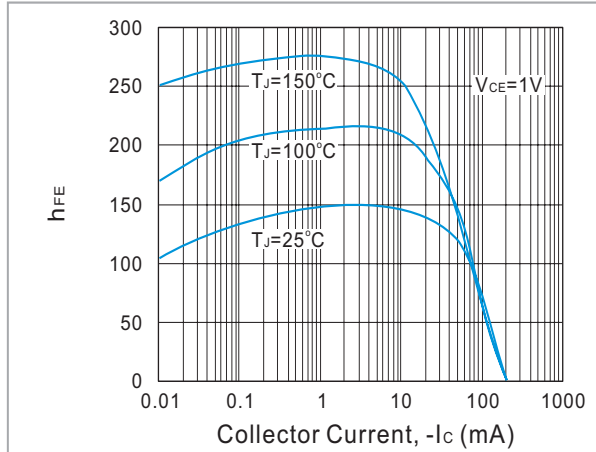


Fig. 1. Typical h_{FE} vs Collector Current

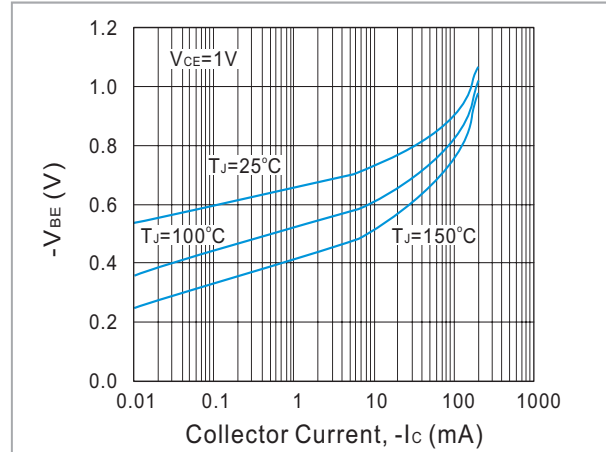


Fig. 2. Typical V_{BE} vs Collector Current

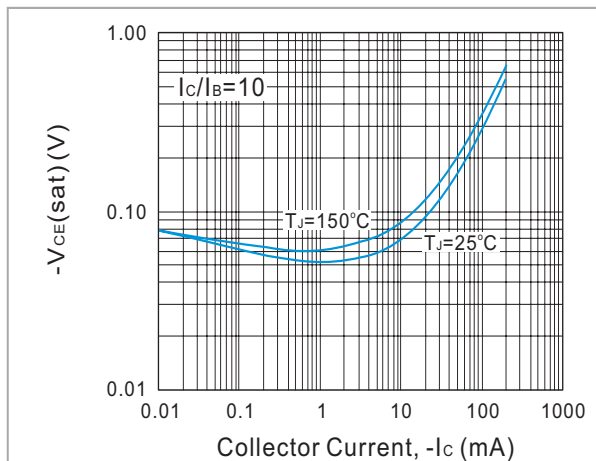


Fig. 3. Typical $V_{CE(sat)}$ vs Collector Current

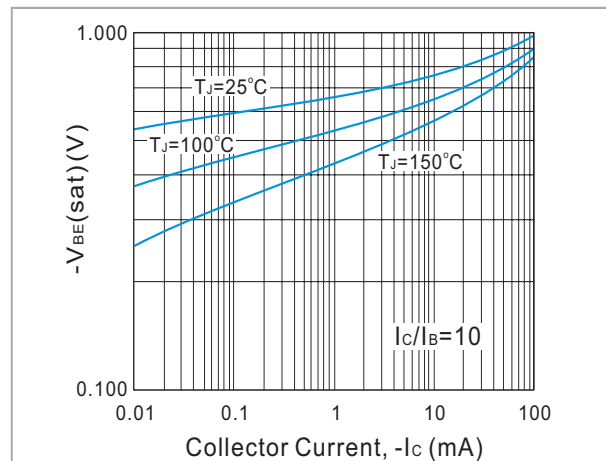


Fig. 4. Typical $V_{BE(sat)}$ vs Collector Current

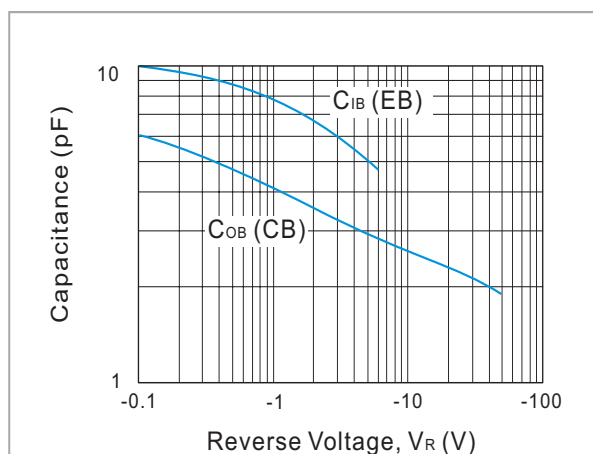
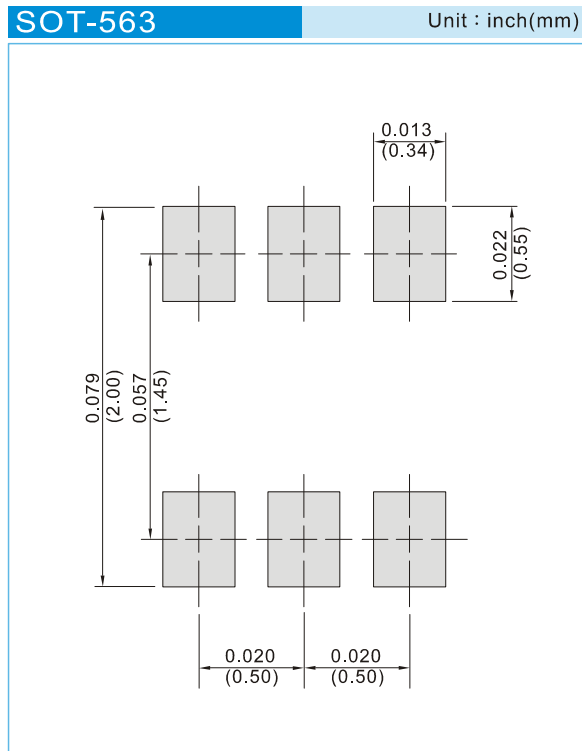


Fig. 5. Typical Capacitances vs Reverse Voltage

MMDT3906TB6

MOUNTING PAD LAYOUT



ORDER INFORMATION

- Packing information

T/R - 4K per 7" plastic Reel

T/R - 10K per 13" plastic Reel

MMDT3906TB6

Part No_packing code_Version

MMDT3906TB6_R1_00001

MMDT3906TB6_R2_00001

For example :

RB500V-40_R2_00001

Part No.

Serial number

Version code means HF

Packing size code means 13"

Packing type means T/R

Packing Code XX				Version Code XXXXX		
Packing type	1 st Code	Packing size code	2 nd Code	HF or RoHS	1 st Code	2 nd ~5 th Code
Tape and Ammunition Box (T/B)	A	N/A	0	HF	0	serial number
Tape and Reel (T/R)	R	7"	1	RoHS	1	serial number
Bulk Packing (B/P)	B	13"	2			
Tube Packing (T/P)	T	26mm	X			
Tape and Reel (Right Oriented) (TRR)	S	52mm	Y			
Tape and Reel (Left Oriented) (TRL)	L	PANASERT T/B CATHODE UP (PBCU)	U			
FORMING	F	PANASERT T/B CATHODE DOWN (PBCD)	D			



MMDT3906TB6

Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Panjit:

[MMDT3906TB6_R2_10001](#) [MMDT3906TB6_R1_00001](#) [MMDT3906TB6_R1_10001](#) [MMDT3906TB6_R2_00001](#)